

Current-induced magnetization in a two-dimensional topological insulator coupled to an environment of localized spins

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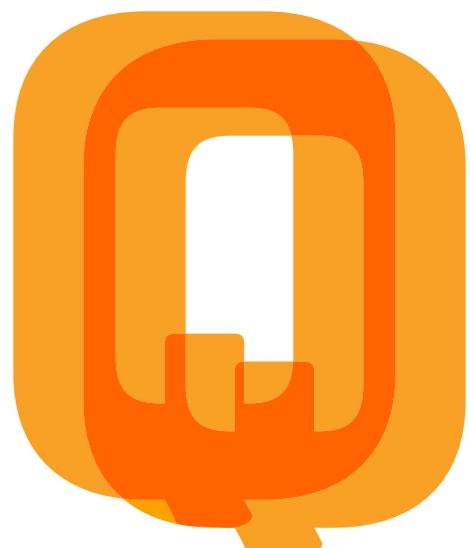
**Cold atoms and beyond, AIAS conference
Friday the 27th of June 2014**

Collaborator: Gloria Platero (Madrid, Spain)

Ref.: - Phys. Rev. B **86**, 035112 (2012)
- Phys. Rev. B **88**, 115411 (2013)



Center for
Quantum
Devices



Outline

- Introduction:
 - What is a 2D topological insulator?
 - Solid state experiments
- A 2D Topological insulator coupled to a spin bath
- Summary

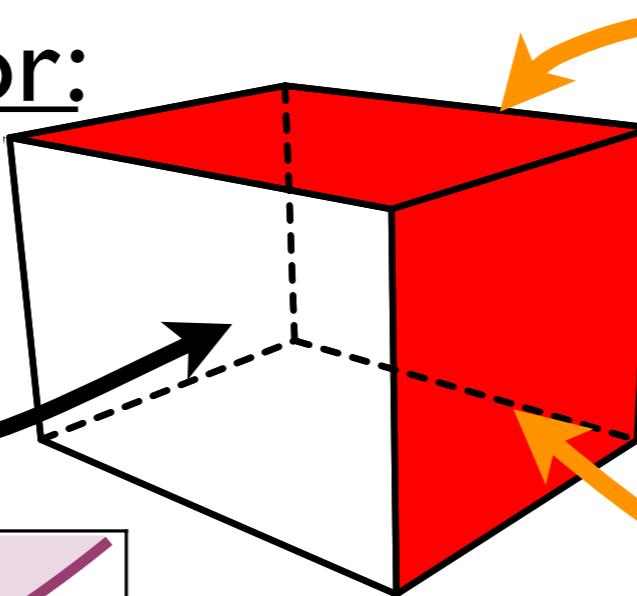
What is a Topological insulator?

Minimal answer:

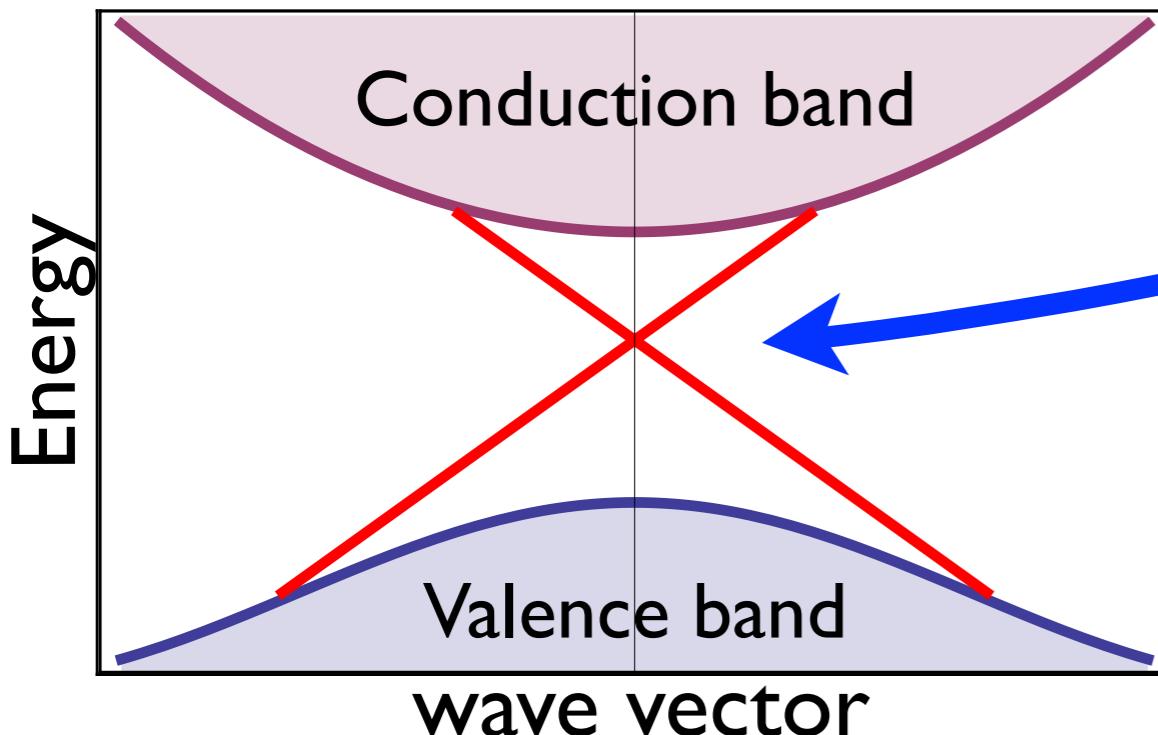
A material with an *insulating bulk* and
metallic states at the boundary

3D Topological Insulator:

Insulating bulk
energy band gap



2D surface states:
Massless Dirac Fermions



Solid state materials:
 Bi_2Se_3 , Bi_2Te_3 , HgTe , BiSb alloys, etc.

Review:

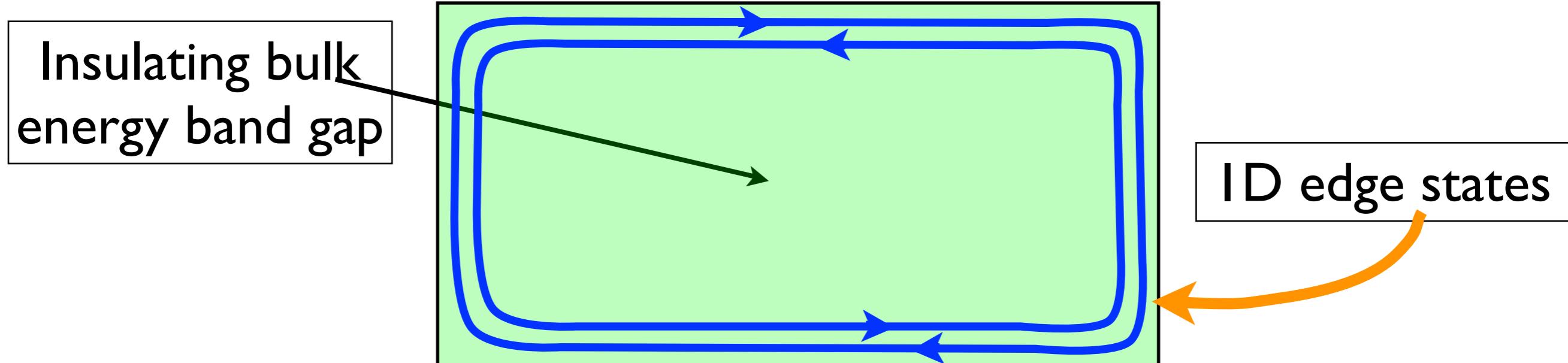
Qi and Zhang, Rev. Mod. Phys. 83, 1057 (2011)

What is a Topological insulator?

Minimal answer:

A material with an *insulating bulk* and
metallic states at the boundary

2D Topological Insulator:



Proposed in Graphene!

Problem: The spin-orbit coupling seems too small experimentally!

Kane and Mele, 95 Phys. Rev. Lett 2005

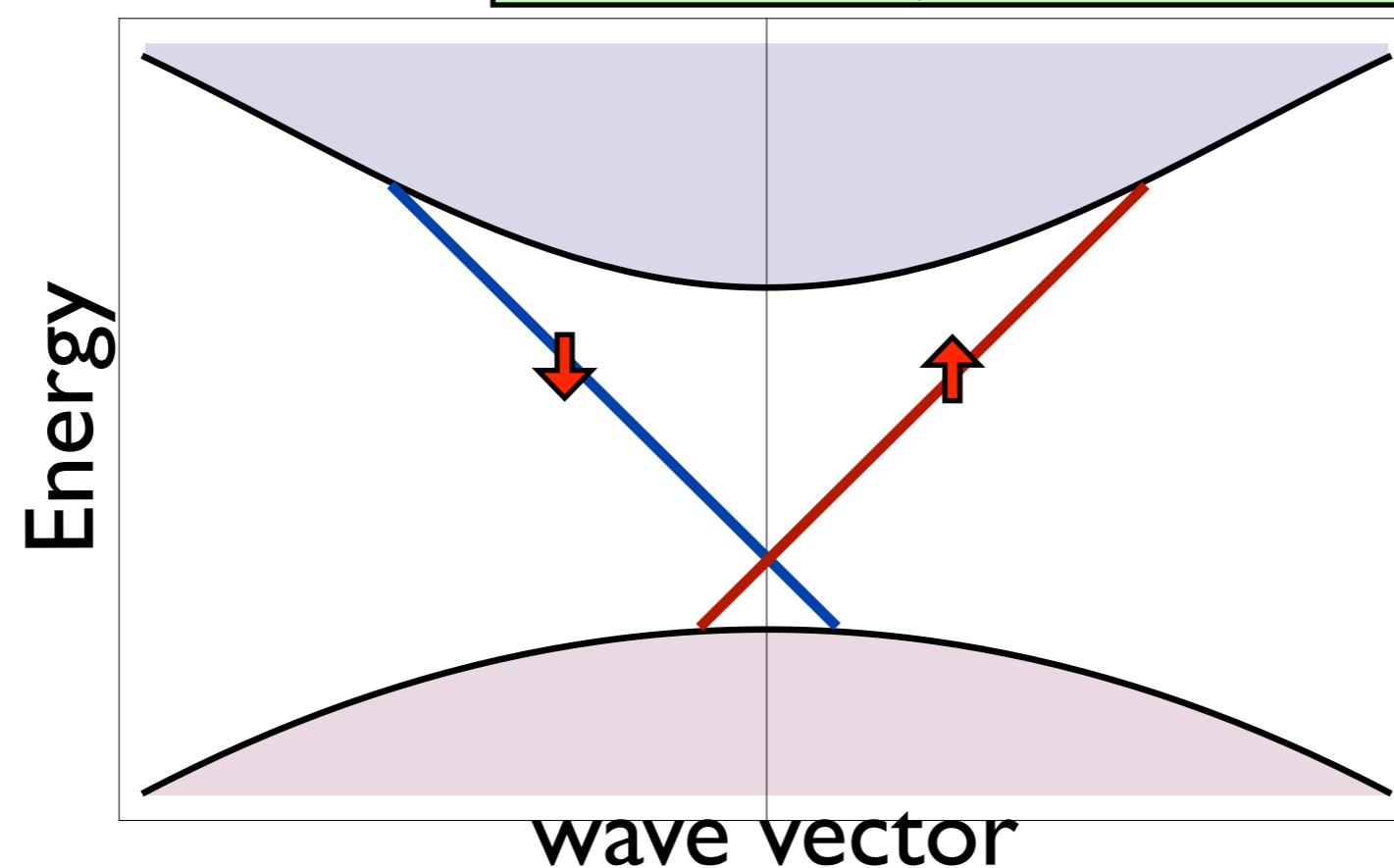
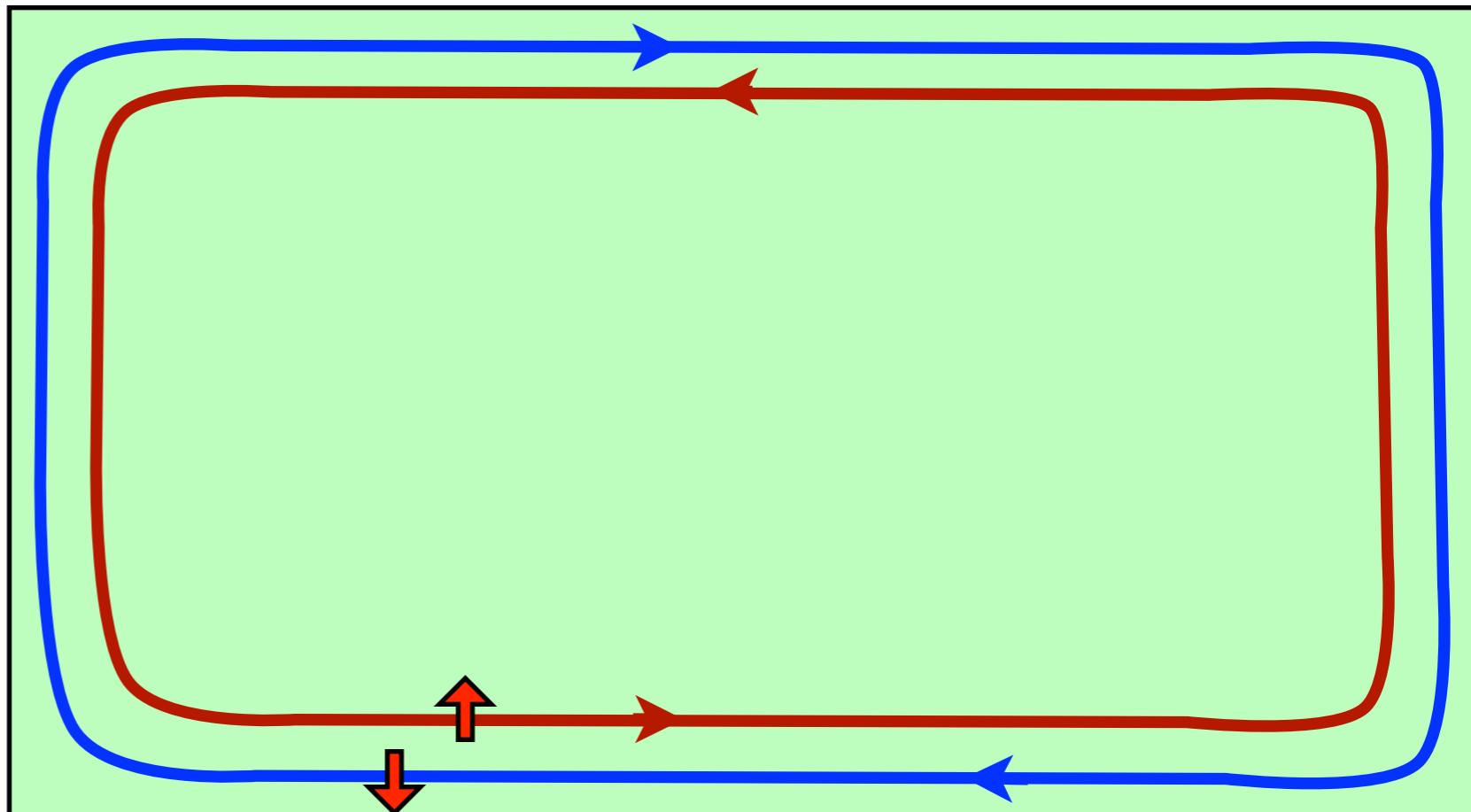
Only a few Solid state materials: HgTe and InAs/GaSb quantum wells.

Review: Qi and Zhang, Rev. Mod. Phys. 83, 1057 (2011)

Spin-momentum locking in topological insulators

Helical edge states:

-Spin up and down are counterpropagating



Time-reversal invariance in topological insulators

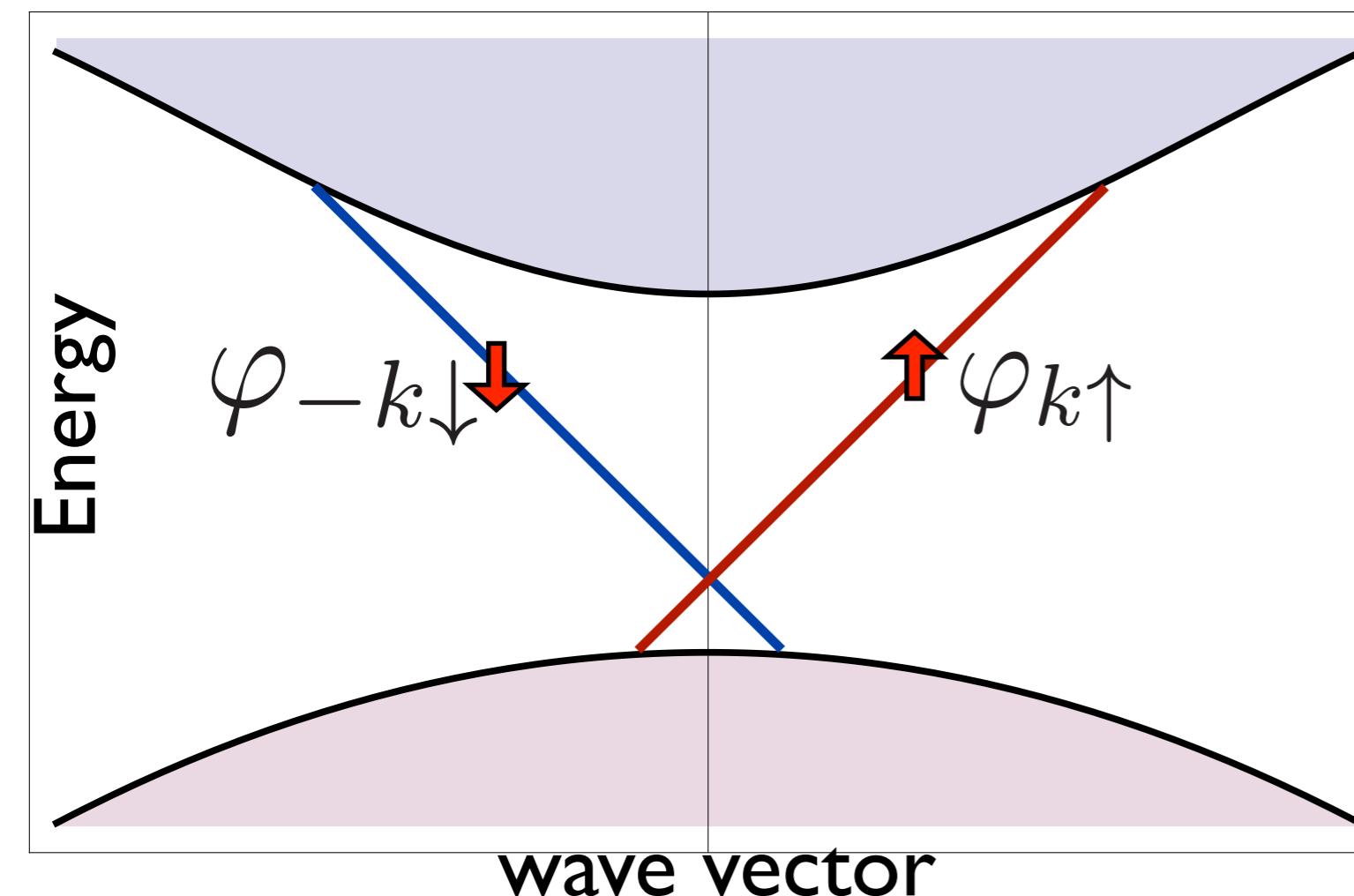
Generally:

Time-reversal symmetry



Kramers degeneracy: Energy levels doubly degenerate

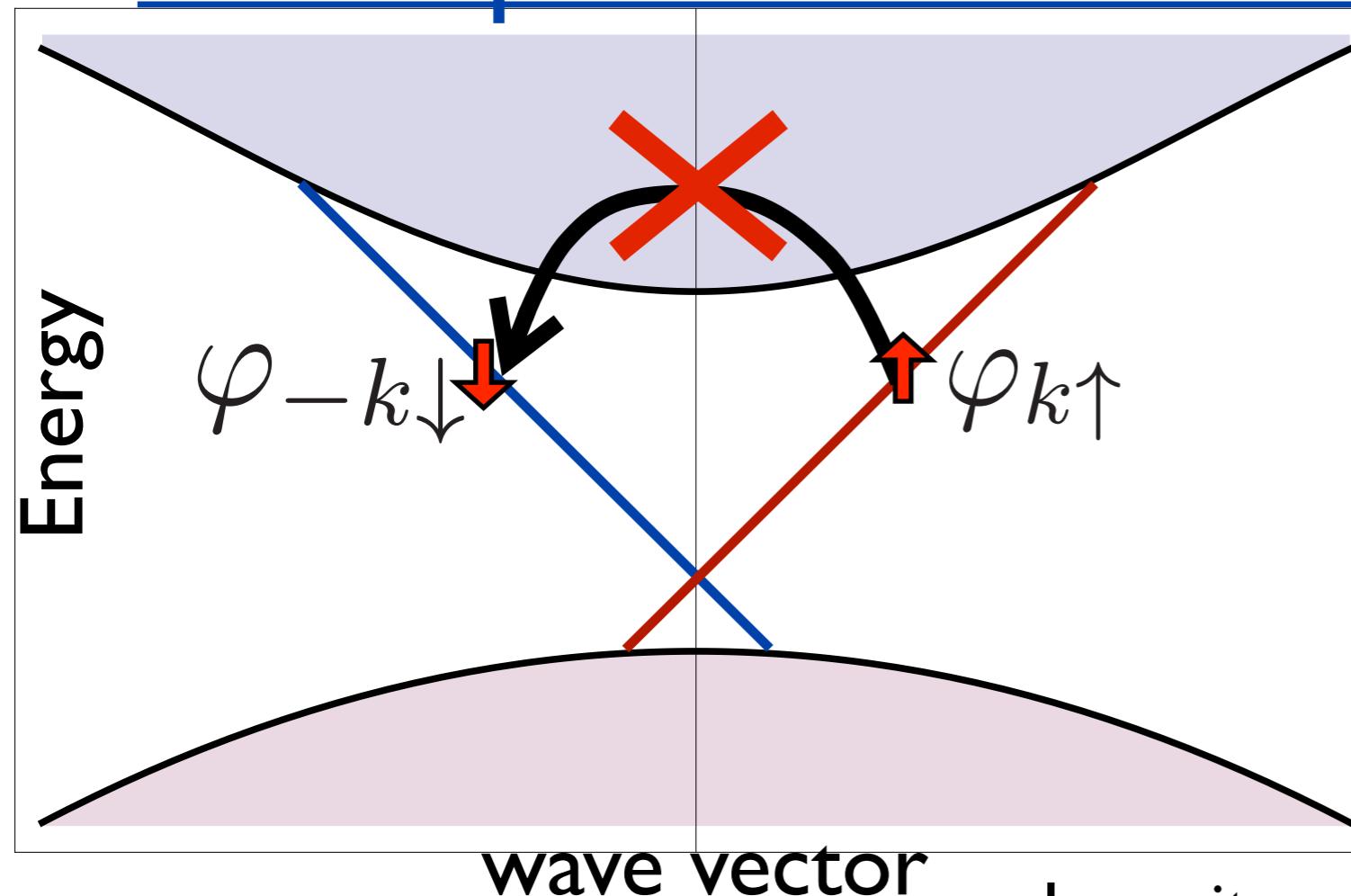
In 2D topological insulators:



Helical edge states
appear in Kramers pairs:

$$\epsilon_{k\uparrow} = \epsilon_{-k\downarrow}$$

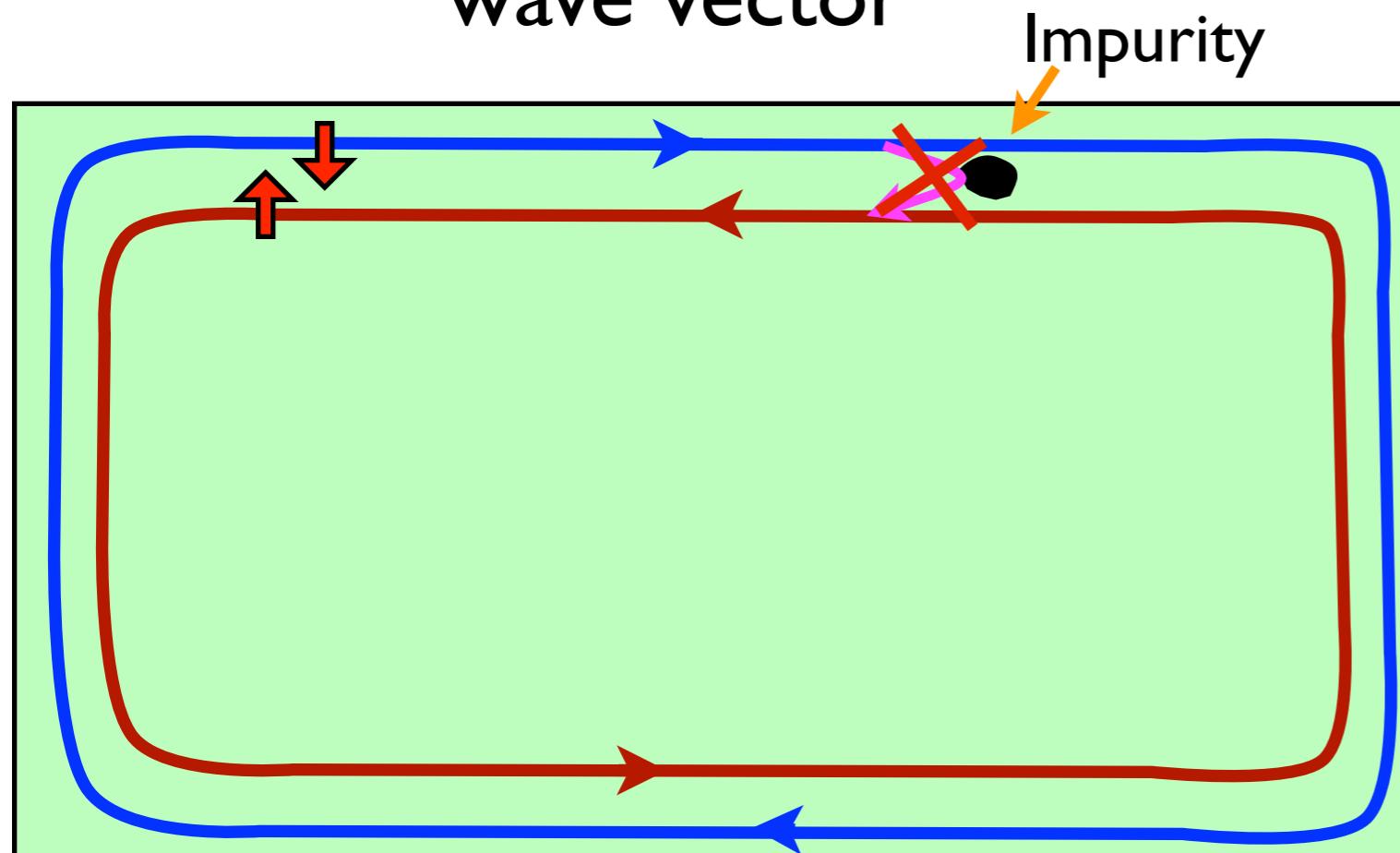
The importance of Time-reversal invariance



No scattering between Kramers pairs:

$$\langle \varphi_{k\uparrow} | V | \varphi_{-k\downarrow} \rangle = 0$$

by time-reversal invariant potentials $\Theta V \Theta^{-1} = V$

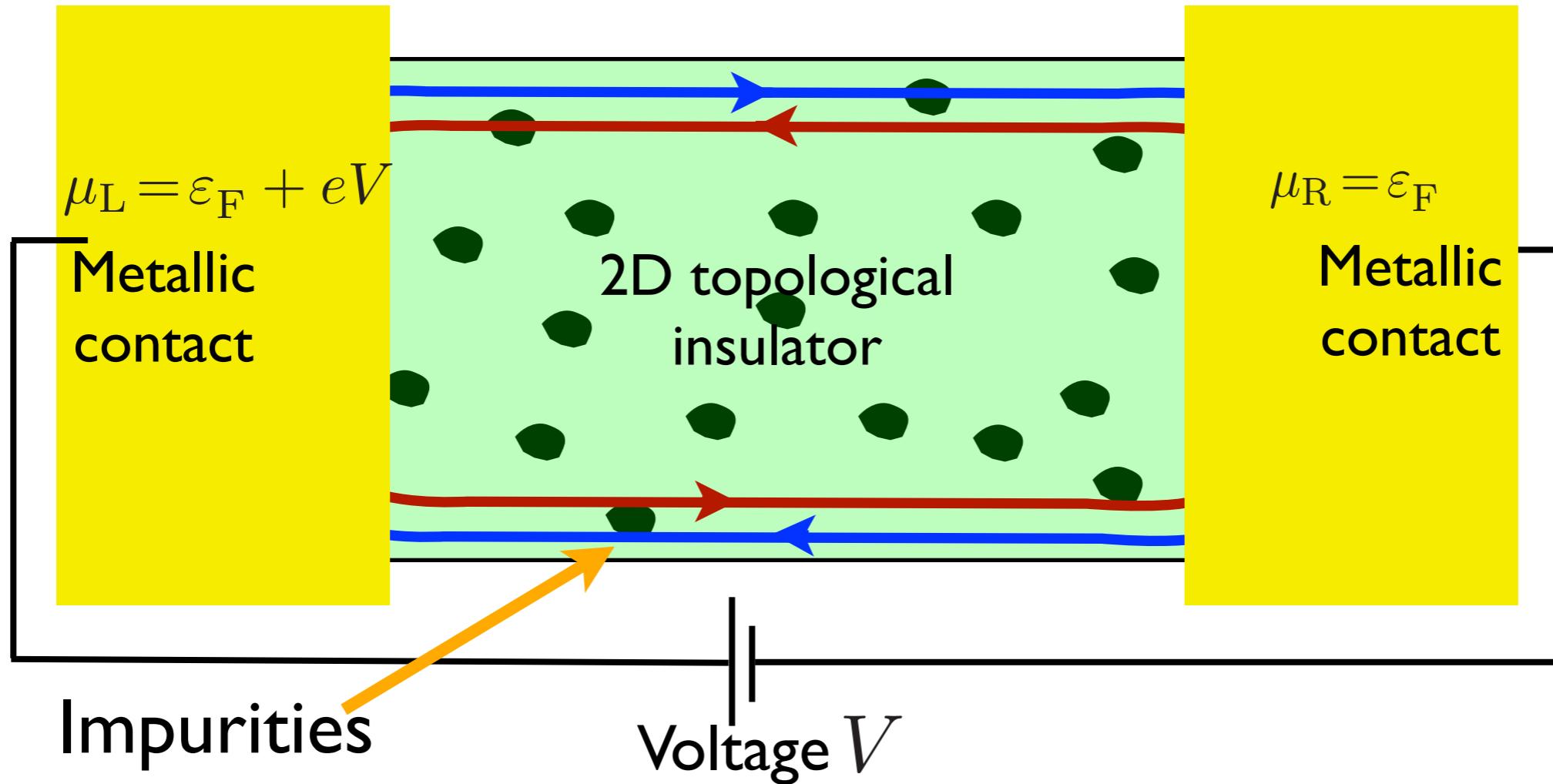


NO elastic backscattering
by impurities etc.

But Inelastic backscattering
is possible!

- Phonon + spin-orbit:
Budich, Dolcini, Recher, Trauzettel PRL (2012);
- e-e interactions + impurity + Spin-orbit:
Schmidt, Rachel, von Oppen, Glazman PRL (2012)

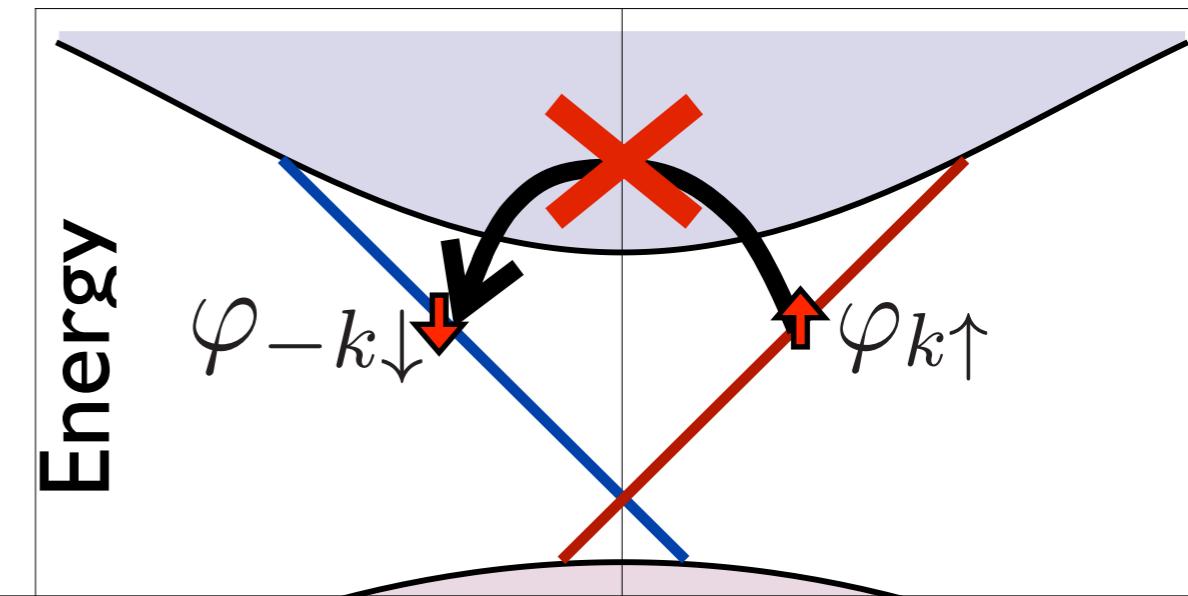
The importance of Time-reversal invariance



Quantized conductance:

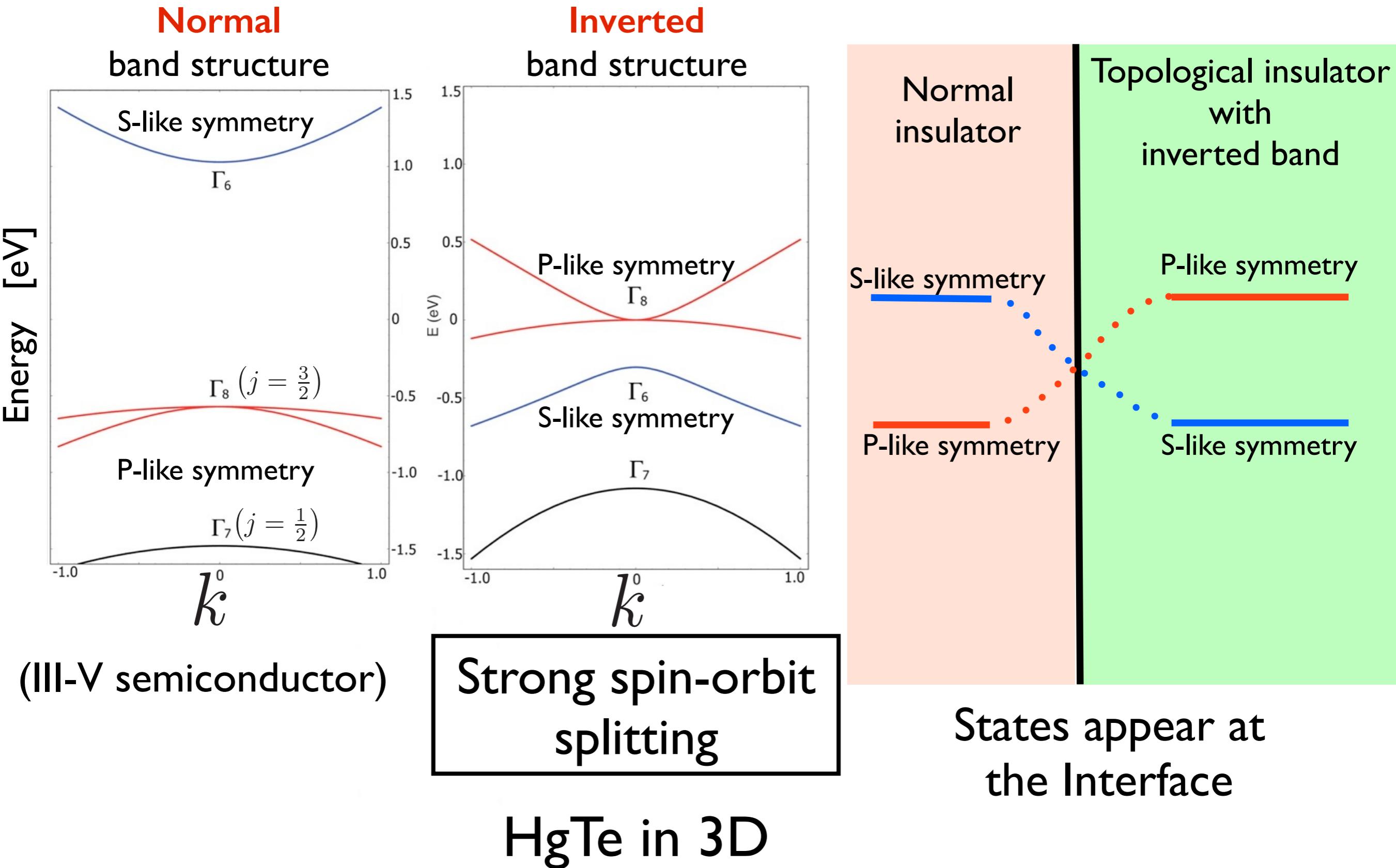
$$G = \frac{2e^2}{h}$$

Also including disorder!



Spin-flip + momentum-reversal needed to backscatter elastically!!

Intuitive explanation for appearance of edge states

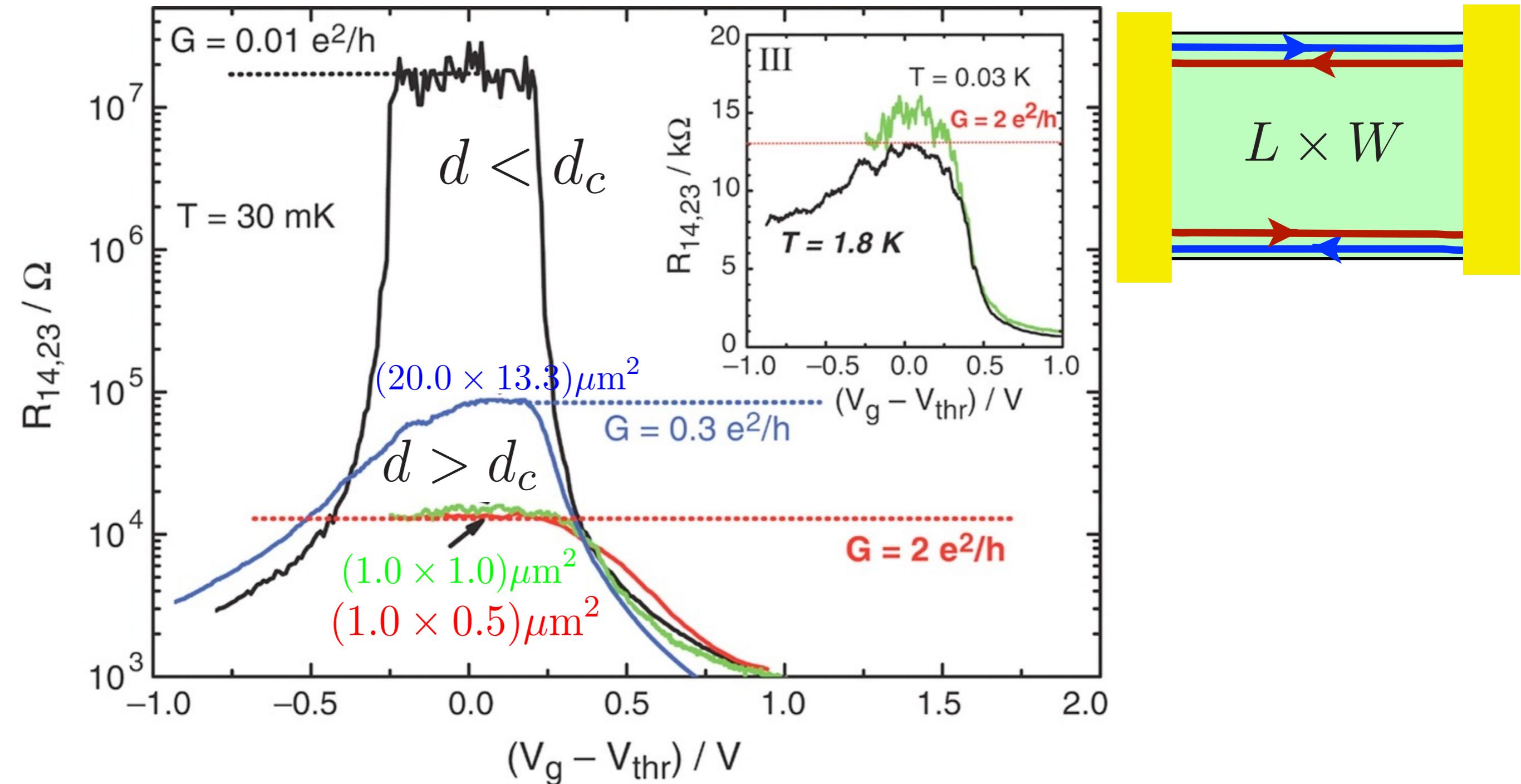


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Experiments in HgTe quantum wells

Molenkamp's group, Science 318, 5851 (2007)



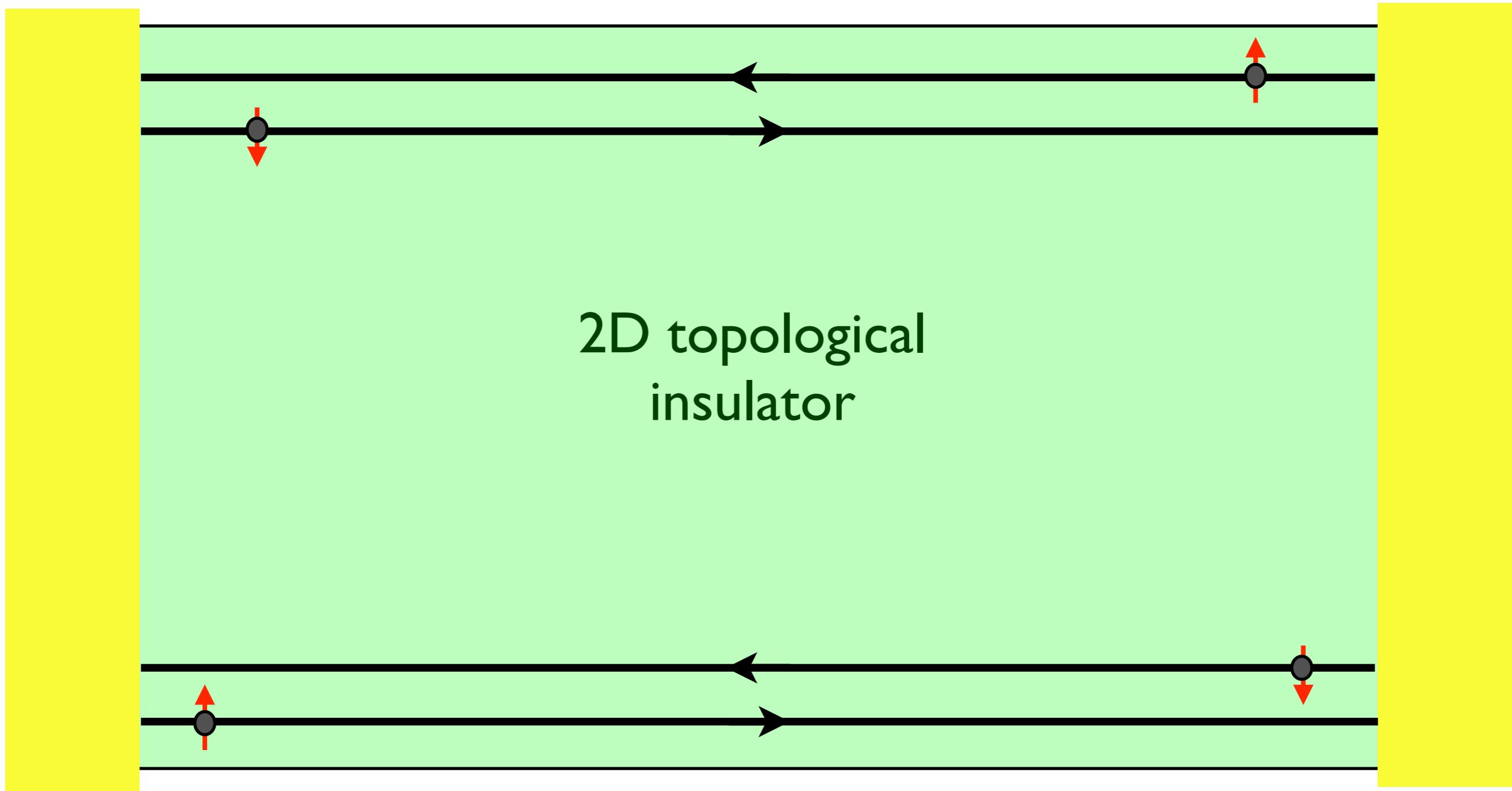
- Further evidence for edge state transport from Hall bar geometry
Molenkamp's group, Science (2009)
- Better conductance quantization in InAs/GaSb quantum wells
Du's group, PRL (2011) + (2014)

Outline

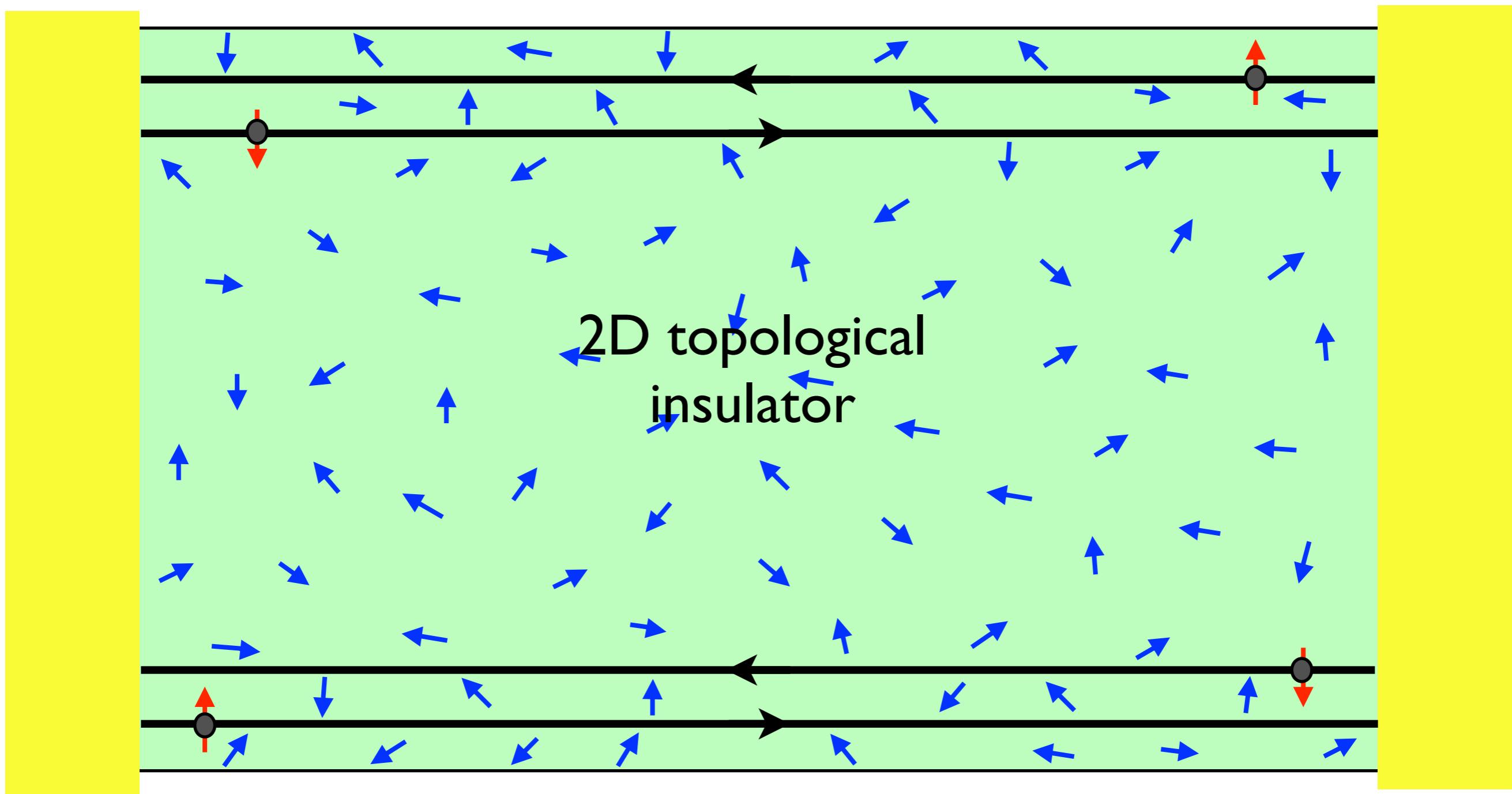
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Setup

2D topological
insulator



Setup

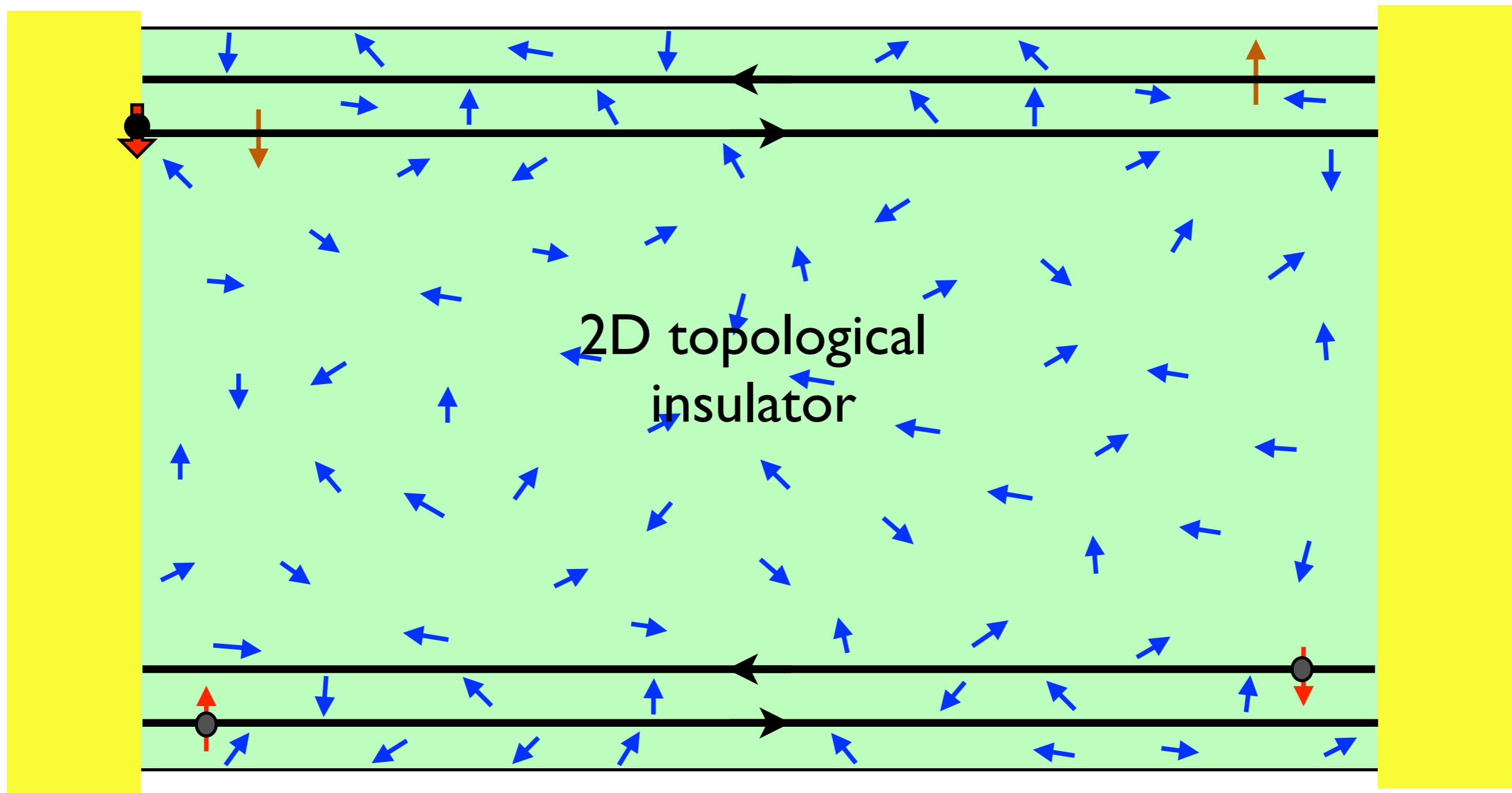


Realizations:

- Magnetic impurities
- Nuclear spins

A.M. Lunde and Platero PRB (2013)

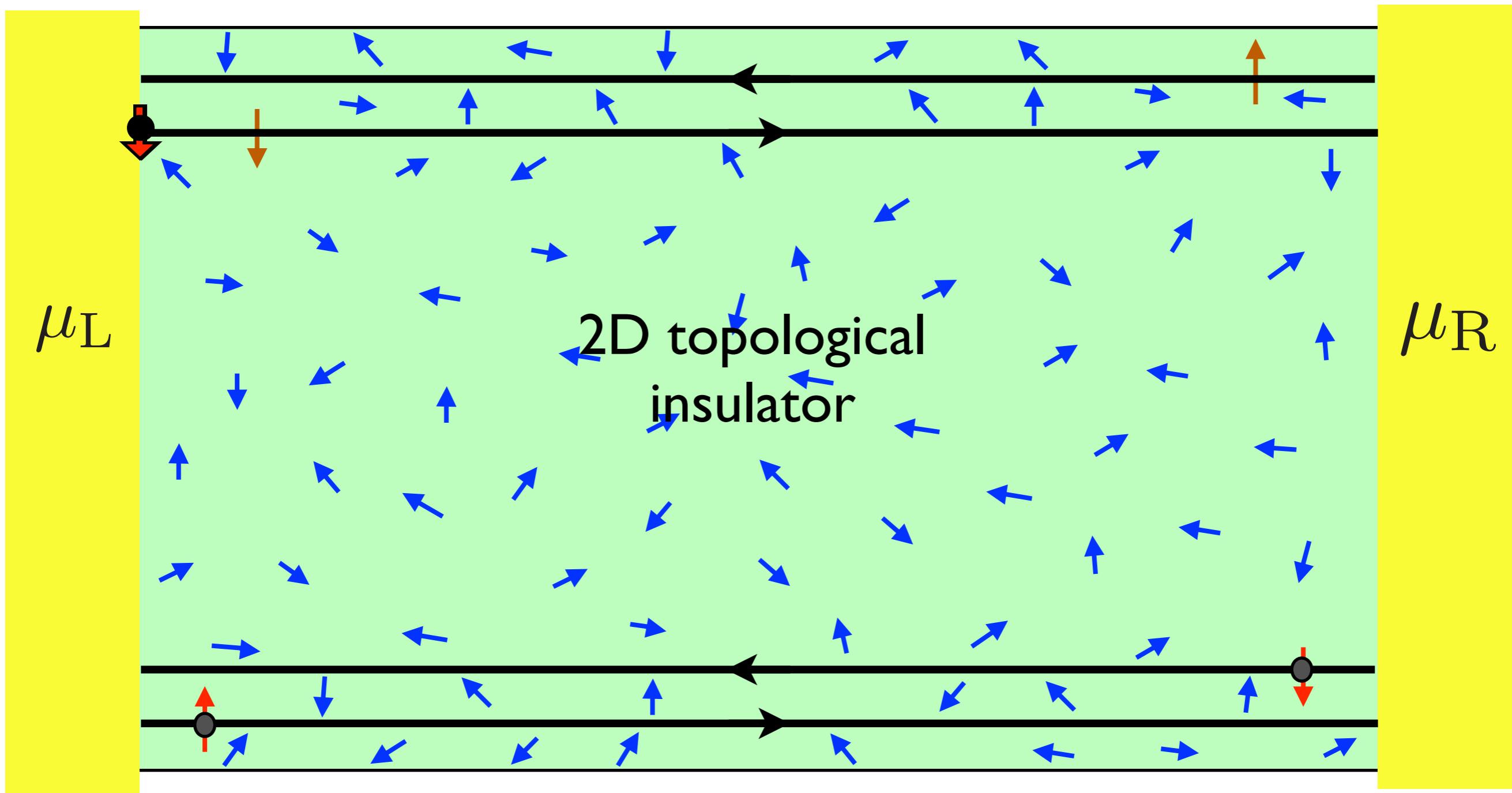
Idea



Fixed spins \Rightarrow spin-flip + momentum-reversal
 \Rightarrow Backscattering!

Voltage induce magnetization at edges

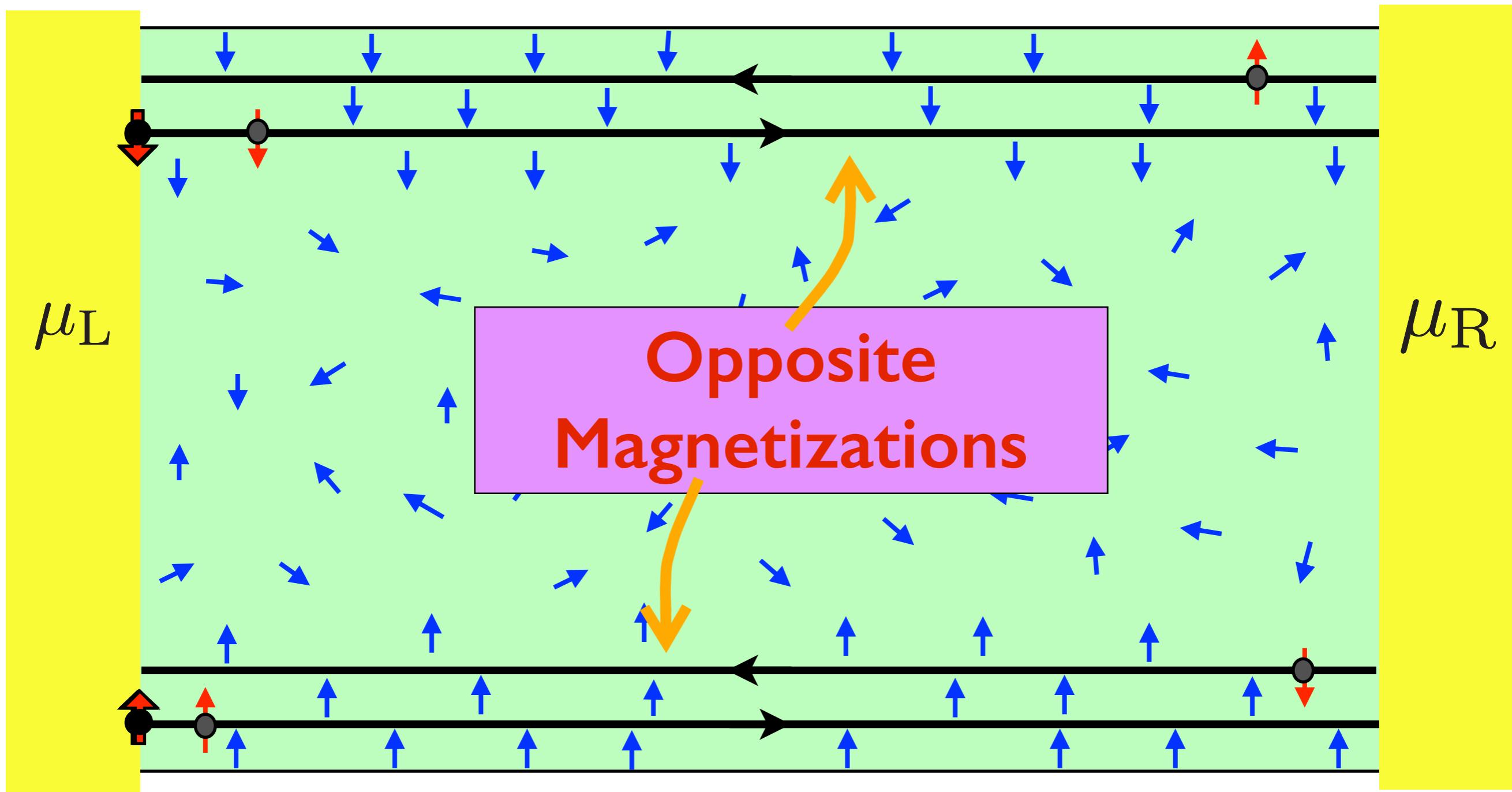
High bias limit: $\mu_L - \mu_R \gg k_B T$ (or low temperature)



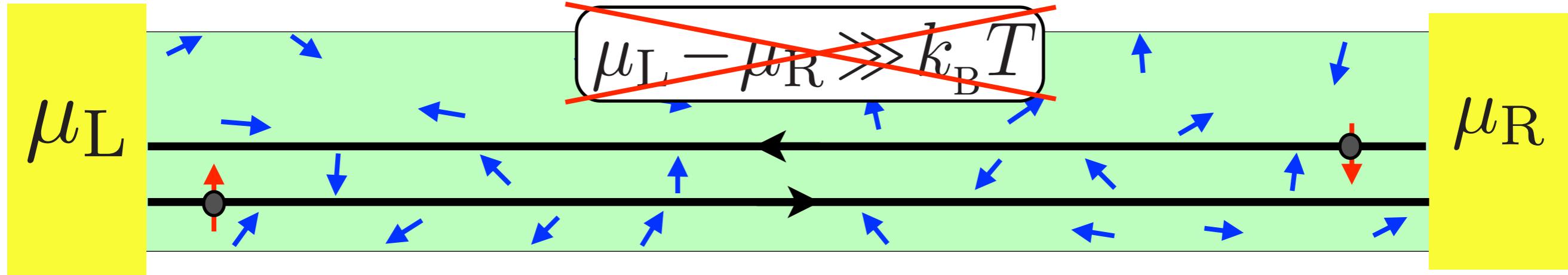
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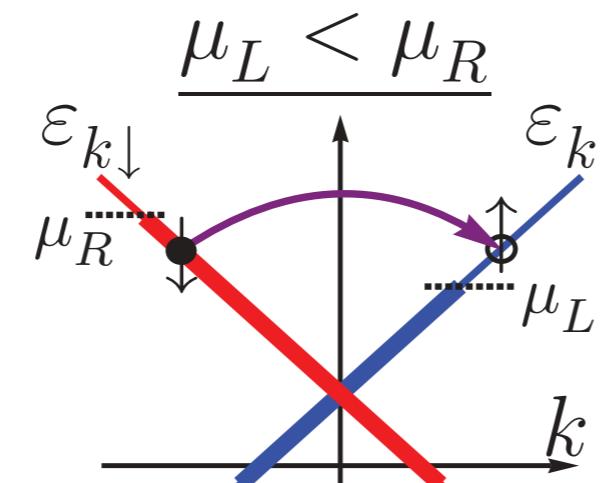
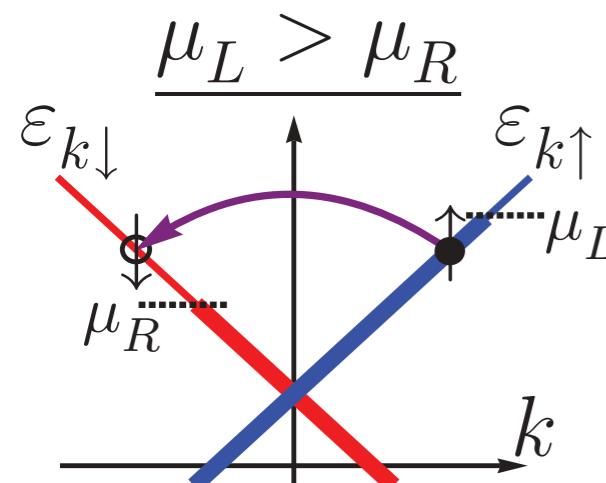
No steady state conductance change!! $G = \frac{2e^2}{h}$



Voltage induced magnetization: Temperature effects



Scattering processes for unmagnetized bath

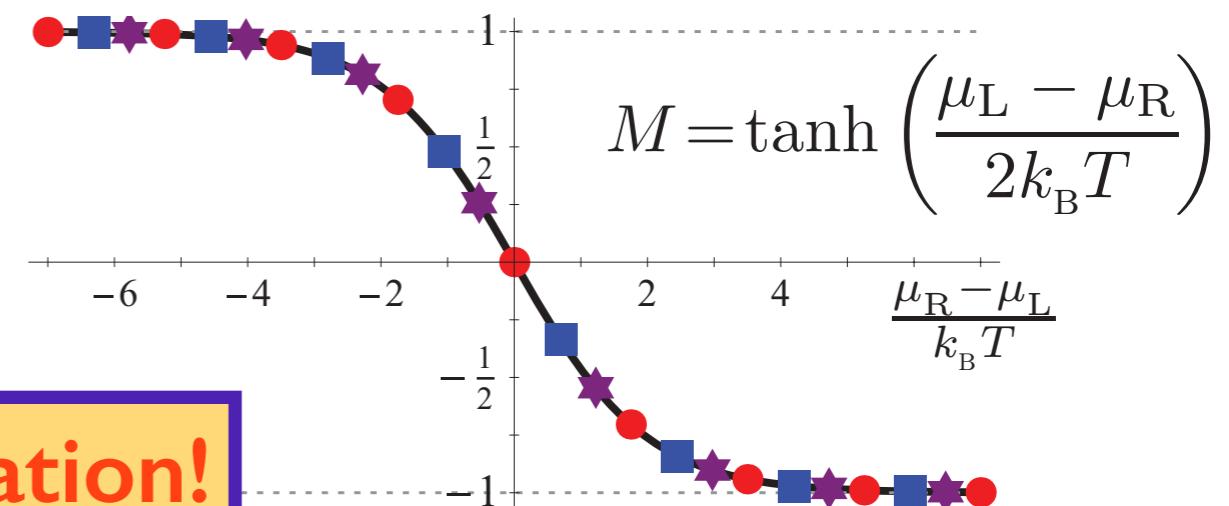


Current: $I = \frac{2e^2}{h} V + \delta I$

$$\delta I = (-e)(\Gamma_{\uparrow\leftarrow\downarrow} - \Gamma_{\downarrow\leftarrow\uparrow})$$

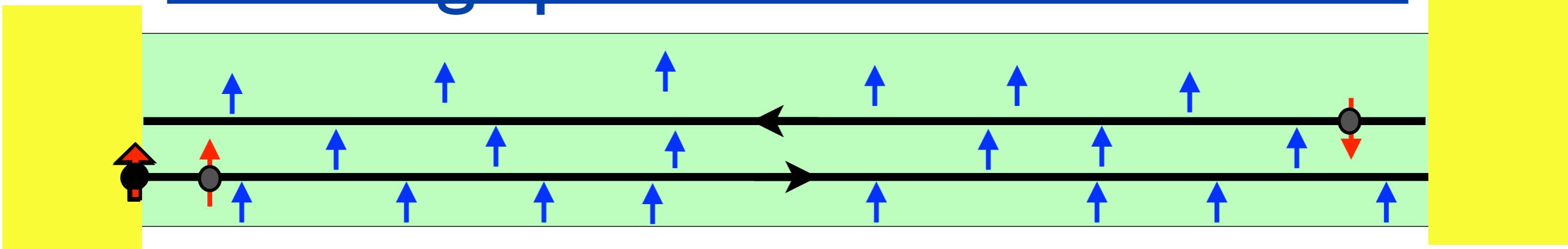
Stationary Magnetization: $\frac{dM}{dt} = \frac{2}{N_s}(\Gamma_{\downarrow\leftarrow\uparrow} - \Gamma_{\uparrow\leftarrow\downarrow}) \implies \Gamma_{\downarrow\leftarrow\uparrow} = \Gamma_{\uparrow\leftarrow\downarrow} \implies \delta I = 0$

$$\left. \begin{aligned} \Gamma_{\uparrow\leftarrow\downarrow} &\propto \frac{N_\uparrow}{N_s} \int dk f_R^0(\varepsilon_{k\uparrow})[1 - f_L^0(\varepsilon_{k\uparrow})] \\ \Gamma_{\downarrow\leftarrow\uparrow} &\propto \frac{N_\downarrow}{N_s} \int dk f_L^0(\varepsilon_{k\uparrow})[1 - f_R^0(\varepsilon_{k\uparrow})] \end{aligned} \right\} \implies$$



Electrically controllable magnetization!

Including spin relaxation in the bath



Possible mechanism: Spin-phonon relaxation

$$\begin{aligned}\text{Current: } I &= \frac{2e^2}{h}V + \delta I \\ \delta I &= (-e)(\Gamma_{\uparrow\leftarrow\downarrow} - \Gamma_{\downarrow\leftarrow\uparrow})\end{aligned}$$

Stationary Magnetization and current change:

$$\frac{dM}{dt} = \frac{2}{N_s}(\Gamma_{\downarrow\leftarrow\uparrow} - \Gamma_{\uparrow\leftarrow\downarrow}) - \frac{\Gamma_r}{N_s}M$$

Spin-relaxation

$$M = \frac{\mu_L - \mu_R}{(\mu_L - \mu_R) \coth\left(\frac{\mu_L - \mu_R}{2k_B T}\right) + \frac{\hbar}{2\eta} \Gamma_r} \quad \text{and} \quad \delta I \neq 0 \quad \text{where} \quad \eta \propto J^2$$

$$G = \frac{e^2}{h} - \frac{e^2}{h} \frac{\pi \hbar \Gamma_r}{2k_B T + \frac{\hbar}{2\eta} \Gamma_r}$$

Summary

- 2D topological insulators exist in the solid state
- 2D topological insulator + spin-bath =
Magnetization at the edge, but no current change!!
- Spin-relaxation in spin-bath gives a small current change.

Ref.: - Phys. Rev. B **86**, 035112 (2012)

- Phys. Rev. B **88**, 115411 (2013)



*Thank you
for your attention!*